E •) (type= semiconductor Corporation - <u>LCMXO3LF-1300E-5UWG36CTR Datasheet</u>



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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	160
Number of Logic Elements/Cells	1280
Total RAM Bits	65536
Number of I/O	28
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	36-UFBGA, WLCSP
Supplier Device Package	36-WLCSP (2.54x2.59)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo3lf-1300e-5uwg36ctr

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong







 MachXO3L/LF-1300, MachXO3L/LF-2100, MachXO3L/LF-6900 and MachXO3L/LF-9400 are similar to MachXO3L/LF-4300. MachXO3L/LF-1300 has a lower LUT count, one PLL, and seven EBR blocks. MachXO3L/LF-2100 has a lower LUT count, one PLL, and eight EBR blocks. MachXO3L/LF-6900 has a higher LUT count, two PLLs, and 26 EBR blocks. MachXO3L/LF-9400 has a higher LUT count, two PLLs, and 48 EBR blocks.

• MachXO3L devices have NVCM, MachXO3LF devices have Flash.

The logic blocks, Programmable Functional Unit (PFU) and sysMEM EBR blocks, are arranged in a two-dimensional grid with rows and columns. Each row has either the logic blocks or the EBR blocks. The PIO cells are located at the periphery of the device, arranged in banks. The PFU contains the building blocks for logic, arithmetic, RAM, ROM, and register functions. The PIOs utilize a flexible I/O buffer referred to as a sysIO buffer that supports operation with a variety of interface standards. The blocks are connected with many vertical and horizontal routing channel resources. The place and route software tool automatically allocates these routing resources.

In the MachXO3L/LF family, the number of sysIO banks varies by device. There are different types of I/O buffers on the different banks. Refer to the details in later sections of this document. The sysMEM EBRs are large, dedicated fast memory blocks. These blocks can be configured as RAM, ROM or FIFO. FIFO support includes dedicated FIFO pointer and flag "hard" control logic to minimize LUT usage.

The MachXO3L/LF registers in PFU and sysI/O can be configured to be SET or RESET. After power up and device is configured, the device enters into user mode with these registers SET/RESET according to the configuration setting, allowing device entering to a known state for predictable system function.

The MachXO3L/LF architecture also provides up to two sysCLOCK Phase Locked Loop (PLL) blocks. These blocks are located at the ends of the on-chip NVCM/Flash block. The PLLs have multiply, divide, and phase shifting capabilities that are used to manage the frequency and phase relationships of the clocks.

MachXO3L/LF devices provide commonly used hardened functions such as SPI controller, I²C controller and timer/ counter.

MachXO3LF devices also provide User Flash Memory (UFM). These hardened functions and the UFM interface to the core logic and routing through a WISHBONE interface. The UFM can also be accessed through the SPI, I²C and JTAG ports.

Every device in the family has a JTAG port that supports programming and configuration of the device as well as access to the user logic. The MachXO3L/LF devices are available for operation from 3.3 V, 2.5 V and 1.2 V power sup-plies, providing easy integration into the overall system.



Figure 2-5. Primary Clocks for MachXO3L/LF Devices



Eight secondary high fanout nets are generated from eight 8:1 muxes as shown in Figure 2-6. One of the eight inputs to the secondary high fanout net input mux comes from dual function clock pins and the remaining seven come from internal routing. The maximum frequency for the secondary clock network is shown in MachXO3L/LF External Switching Characteristics table.



Figure 2-11. Group of Four Programmable I/O Cells





Output Register Block

The output register block registers signals from the core of the device before they are passed to the sysIO buffers.

Left, Top, Bottom Edges

In SDR mode, D0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type register or latch.

In DDR generic mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the same clock is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-12 shows the output register block on the left, top and bottom edges.

Figure 2-12. MachXO3L/LF Output Register Block Diagram (PIO on the Left, Top and Bottom Edges)



Tri-state Register Block

The tri-state register block registers tri-state control signals from the core of the device before they are passed to the sysIO buffers. The block contains a register for SDR operation. In SDR, TD input feeds one of the flip-flops that then feeds the output.



Input Gearbox

Each PIC on the bottom edge has a built-in 1:8 input gearbox. Each of these input gearboxes may be programmed as a 1:7 de-serializer or as one IDDRX4 (1:8) gearbox or as two IDDRX2 (1:4) gearboxes. Table 2-9 shows the gearbox signals.

Table 2-9. Input Gearbox Signal List

Name	I/O Type	Description
D	Input	High-speed data input after programmable delay in PIO A input register block
ALIGNWD	Input	Data alignment signal from device core
SCLK	Input	Slow-speed system clock
ECLK[1:0]	Input	High-speed edge clock
RST	Input	Reset
Q[7:0]	Output	Low-speed data to device core: Video RX(1:7): Q[6:0] GDDRX4(1:8): Q[7:0] GDDRX2(1:4)(IOL-A): Q4, Q5, Q6, Q7 GDDRX2(1:4)(IOL-C): Q0, Q1, Q2, Q3

These gearboxes have three stage pipeline registers. The first stage registers sample the high-speed input data by the high-speed edge clock on its rising and falling edges. The second stage registers perform data alignment based on the control signals UPDATE and SEL0 from the control block. The third stage pipeline registers pass the data to the device core synchronized to the low-speed system clock. Figure 2-13 shows a block diagram of the input gearbox.



Figure 2-13. Input Gearbox



More information on the input gearbox is available in TN1281, Implementing High-Speed Interfaces with MachXO3 Devices.



Output Gearbox

Each PIC on the top edge has a built-in 8:1 output gearbox. Each of these output gearboxes may be programmed as a 7:1 serializer or as one ODDRX4 (8:1) gearbox or as two ODDRX2 (4:1) gearboxes. Table 2-10 shows the gearbox signals.

Table 2-10. Output Gearbox Signal List

Name	I/O Type	Description
Q	Output	High-speed data output
D[7:0]	Input	Low-speed data from device core
Video TX(7:1): D[6:0]		
GDDRX4(8:1): D[7:0]		
GDDRX2(4:1)(IOL-A): D[3:0]		
GDDRX2(4:1)(IOL-C): D[7:4]		
SCLK	Input	Slow-speed system clock
ECLK [1:0]	Input	High-speed edge clock
RST	Input	Reset

The gearboxes have three stage pipeline registers. The first stage registers sample the low-speed input data on the low-speed system clock. The second stage registers transfer data from the low-speed clock registers to the high-speed clock registers. The third stage pipeline registers controlled by high-speed edge clock shift and mux the high-speed data out to the sysIO buffer. Figure 2-14 shows the output gearbox block diagram.



Figure 2-14. Output Gearbox



More information on the output gearbox is available in TN1281, Implementing High-Speed Interfaces with MachXO3 Devices.



TraceID

Each MachXO3L/LF device contains a unique (per device), TraceID that can be used for tracking purposes or for IP security applications. The TraceID is 64 bits long. Eight out of 64 bits are user-programmable, the remaining 56 bits are factory-programmed. The TraceID is accessible through the EFB WISHBONE interface and can also be accessed through the SPI, I²C, or JTAG interfaces.

Density Shifting

The MachXO3L/LF family has been designed to enable density migration within the same package. Furthermore, the architecture ensures a high success rate when performing design migration from lower density devices to higher density devices. In many cases, it is also possible to shift a lower utilization design targeted for a high-density device to a lower density device. However, the exact details of the final resource utilization will impact the likely success in each case. When migrating from lower to higher density or higher to lower density, ensure to review all the power supplies and NC pins of the chosen devices. For more details refer to the MachXO3 migration files.



LVDS Emulation

MachXO3L/LF devices can support LVDS outputs via emulation (LVDS25E). The output is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all devices. The scheme shown in Figure 3-1 is one possible solution for LVDS standard implementation. Resistor values in Figure 3-1 are industry standard values for 1% resistors.





Note: All resistors are ±1%.

Table 3-1. LVDS25E DC Conditions

Over Recommended Operating Conditions

Parameter	Description	Тур.	Units
Z _{OUT}	Output impedance	20	Ohms
R _S	Driver series resistor	158	Ohms
R _P	Driver parallel resistor	140	Ohms
R _T	Receiver termination	100	Ohms
V _{OH}	Output high voltage	1.43	V
V _{OL}	Output low voltage	1.07	V
V _{OD}	Output differential voltage	0.35	V
V _{CM}	Output common mode voltage	1.25	V
Z _{BACK}	Back impedance	100.5	Ohms
I _{DC}	DC output current	6.03	mA



MIPI D-PHY Emulation

MachXO3L/LF devices can support MIPI D-PHY unidirectional HS (High Speed) and bidirectional LP (Low Power) inputs and outputs via emulation. In conjunction with external resistors High Speed IOs use the LVDS25E buffer and Low Power IOs use the LVCMOS buffers. The scheme shown in Figure 3-4 is one possible solution for MIPI D-PHY Receiver implementation. The scheme shown in Figure 3-5 is one possible solution for MIPI D-PHY Transmitter implementation.

Figure 3-4. MIPI D-PHY Input Using External Resistors



Table 3-4. MIPI DC Conditions¹

	Description	Min.	Тур.	Max.	Units			
Receiver								
External Terminatio	n							
RT	1% external resistor with VCCIO=2.5 V		50	—	Ohms			
	1% external resistor with VCCIO=3.3 V	—	50	—	Ohms			
High Speed								
VCCIO	VCCIO of the Bank with LVDS Emulated input buffer	—	2.5	—	V			
	VCCIO of the Bank with LVDS Emulated input buffer	—	3.3	—	V			
VCMRX	Common-mode voltage HS receive mode	150	200	250	mV			
VIDTH	Differential input high threshold	—	—	100	mV			
VIDTL	Differential input low threshold	-100	—	—	mV			
VIHHS	Single-ended input high voltage		—	300	mV			
VILHS	Single-ended input low voltage	100	—	—	mV			
ZID	Differential input impedance	80	100	120	Ohms			



MachXO3L/LF External Switching Characteristics – C/E Devices^{1, 2, 3, 4, 5, 6, 10}

			-6		-5		
Parameter	Description	Device	Min.	Max.	Min.	Max.	Units
Clocks							
Primary Clo	cks						-
f _{MAX_PRI} ⁷	Frequency for Primary Clock Tree	All MachXO3L/LF devices	_	388	_	323	MHz
t _{W_PRI}	Clock Pulse Width for Primary Clock	All MachXO3L/LF devices	0.5		0.6		ns
		MachXO3L/LF-1300		867	_	897	ps
		MachXO3L/LF-2100		867		897	ps
t _{SKEW_PRI}	Primary Clock Skew Within a Device	MachXO3L/LF-4300	_	865	-	892	ps
		MachXO3L/LF-6900	_	902	-	942	ps
		MachXO3L/LF-9400	_	908	-	950	ps
Edge Clock							
f _{MAX_EDGE} ⁷	Frequency for Edge Clock	MachXO3L/LF		400	_	333	MHz
Pin-LUT-Pin	Propagation Delay						
t _{PD}	Best case propagation delay through one LUT-4	All MachXO3L/LF devices		6.72		6.96	ns
General I/O	Pin Parameters (Using Primary Clock with	out PLL)					
		MachXO3L/LF-1300	—	7.46	—	7.66	ns
	Clock to Output - PIO Output Register	MachXO3L/LF-2100	_	7.46	_	7.66	ns
t _{co}		MachXO3L/LF-4300	_	7.51		7.71	ns
		MachXO3L/LF-6900	_	7.54		7.75	ns
		MachXO3L/LF-9400	_	7.53		7.83	ns
		MachXO3L/LF-1300	-0.20	_	-0.20		ns
		MachXO3L/LF-2100	-0.20	_	-0.20		ns
t _{SU}	Clock to Data Setup - PIO Input Register	MachXO3L/LF-4300	-0.23	_	-0.23		ns
		MachXO3L/LF-6900	-0.23		-0.23		ns
		MachXO3L/LF-9400	-0.24		-0.24		ns
		MachXO3L/LF-1300	1.89		2.13		ns
		MachXO3L/LF-2100	1.89	_	2.13		ns
t _H	Clock to Data Hold - PIO Input Register	MachXO3L/LF-4300	1.94	_	2.18		ns
		MachXO3L/LF-6900	1.98	_	2.23		ns
		MachXO3L/LF-9400	1.99	_	2.24		ns
		MachXO3L/LF-1300	1.61	_	1.76		ns
		MachXO3L/LF-2100	1.61	_	1.76		ns
t _{SU DEL}	Clock to Data Setup - PIO Input Register	MachXO3L/LF-4300	1.66	_	1.81		ns
	with Data input Delay	MachXO3L/LF-6900	1.53	_	1.67		ns
		MachXO3L/LF-9400	1.65	_	1.80		ns
		MachXO3L/LF-1300	-0.23	_	-0.23		ns
		MachXO3L/LF-2100	-0.23	—	-0.23	_	ns
^t H DEL	Clock to Data Hold - PIO Input Register with	MachXO3L/LF-4300	-0.25	_	-0.25	_	ns
	Input Data Delay	MachXO3L/LF-6900	-0.21	_	-0.21	_	ns
		MachXO3L/LF-9400	-0.24	_	-0.24	_	ns
f _{MAX_IO}	Clock Frequency of I/O and PFU Register	All MachXO3L/LF devices	—	388	—	323	MHz

Over Recommended Operating Conditions



			_	6	_5		
Parameter	Description	Device	Min.	Max.	Min.	Max.	Units
MIPI D-PHY	Inputs with Clock and Data Centered at F	Pin Using PCLK Pin for Clo	ck Input	-			<u> </u>
GDDRX4_R	K.ECLK.Centered ^{10, 11, 12}		1	1	1	1	T
t _{SU} ¹⁵	Input Data Setup Before ECLK		0.200		0.200	—	UI
t _{HO} ¹⁵	Input Data Hold After ECLK	All MachXO3L/LE	0.200	—	0.200	—	UI
f _{DATA} ¹⁴	MIPI D-PHY Input Data Speed	devices, bottom side only		900	—	900	Mbps
f _{DDRX4} ¹⁴	MIPI D-PHY ECLK Frequency		—	450	—	450	MHz
f _{SCLK} ¹⁴	SCLK Frequency		_	112.5	-	112.5	MHz
Generic DD	R Outputs with Clock and Data Aligned at	Pin Using PCLK Pin for Clo	ck Input	– GDDF	RX1_TX.	SCLK.A	ligned ⁸
t _{DIA}	Output Data Invalid After CLK Output		—	0.520	—	0.550	ns
t _{DIB}	Output Data Invalid Before CLK Output	All MachXO3L/LF		0.520	—	0.550	ns
f _{DATA}	DDRX1 Output Data Speed	all sides		300	—	250	Mbps
f _{DDRX1}	DDRX1 SCLK frequency			150	—	125	MHz
Generic DDF	Outputs with Clock and Data Centered at	Pin Using PCLK Pin for Clo	ck Input	– GDDR	X1_TX.9	SCLK.Ce	entered ⁸
t _{DVB}	Output Data Valid Before CLK Output		1.210		1.510	—	ns
t _{DVA}	Output Data Valid After CLK Output	All MachXO3L/LF	1.210		1.510	—	ns
f _{DATA}	DDRX1 Output Data Speed	devices,	_	300	—	250	Mbps
f _{DDRX1}	DDRX1 SCLK Frequency (minimum limited by PLL)	— all sides	_	150	_	125	MHz
Generic DDF	X2 Outputs with Clock and Data Aligned a	at Pin Using PCLK Pin for Clo	ock Inpu	t – GDD	RX2_TX	ECLK.A	
t _{DIA}	Output Data Invalid After CLK Output		<u> </u>	0.200	—	0.215	ns
t _{DIB}	Output Data Invalid Before CLK Output	_		0.200	_	0.215	ns
f _{DATA}	DDRX2 Serial Output Data Speed	MachXO3L/LF devices,		664	_	554	Mbps
foogy2	DDRX2 ECLK frequency	top side only		332	_	277	MHz
fsci k	SCLK Frequency			166	_	139	MHz
Generic DD	RX2 Outputs with Clock and Data Center	ed at Pin Using PCLK Pin fo	or Clock	Input –			
GDDRX2_T	(.ECLK.Centered ^{8, 9}	0		•			
t _{DVB}	Output Data Valid Before CLK Output		0.535	—	0.670	—	ns
t _{DVA}	Output Data Valid After CLK Output		0.535	—	0.670	—	ns
f _{DATA}	DDRX2 Serial Output Data Speed	MachXO3L/LF devices,		664	—	554	Mbps
f _{DDRX2}	DDRX2 ECLK Frequency (minimum limited by PLL)	top side only	_	332	—	277	MHz
f _{SCLK}	SCLK Frequency			166	—	139	MHz
Generic DD GDDRX4_TX	RX4 Outputs with Clock and Data Aligned	d at Pin Using PCLK Pin for	Clock I	nput –			
t _{DIA}	Output Data Invalid After CLK Output		_	0.200	_	0.215	ns
t _{DIB}	Output Data Invalid Before CLK Output	7		0.200	_	0.215	ns
f _{DATA}	DDRX4 Serial Output Data Speed	MachXO3L/LF devices,	_	800	_	630	Mbps
f _{DDBX4}	DDRX4 ECLK Frequency		<u> </u>	400	_	315	MHz
fscik	SCLK Frequency		<u> </u>	100		79	MHz



Figure 3-6. Receiver GDDR71_RX. Waveforms



Figure 3-7. Transmitter GDDR71_TX. Waveforms





NVCM/Flash Download Time^{1, 2}

Symbol	Parameter	Device	Тур.	Units
t _{REFRESH}	POR to Device I/O Active	LCMXO3L/LF-640	1.9	ms
		LCMXO3L/LF-1300	1.9	ms
		LCMXO3L/LF-1300 256-Ball Package	1.4	ms
		LCMXO3L/LF-2100	1.4	ms
		LCMXO3L/LF-2100 324-Ball Package	2.4	ms
		LCMXO3L/LF-4300	2.4	ms
		LCMXO3L/LF-4300 400-Ball Package	3.8	ms
		LCMXO3L/LF-6900	3.8	ms
		LCMXO3L/LF-9400C	5.2	ms

1. Assumes sysMEM EBR initialized to an all zero pattern if they are used.

2. The NVCM/Flash download time is measured starting from the maximum voltage of POR trip point.



sysCONFIG Port Timing Specifications

Symbol	Parameter		Min.	Max.	Units
All Configuration Mo	odes				
t _{PRGM}	PROGRAMN low p	ulse accept	55	_	ns
t _{PRGMJ}	PROGRAMN low p	ulse rejection	_	25	ns
t _{INITL}	INITN low time	LCMXO3L/LF-640/ LCMXO3L/LF-1300	—	55	us
		LCMXO3L/LF-1300 256-Ball Package/ LCMXO3L/LF-2100	_	70	us
		LCMXO3L/LF-2100 324-Ball Package/ LCMXO3-4300	_	105	us
		LCMXO3L/LF-4300 400-Ball Package/ LCMXO3-6900	_	130	us
		LCMXO3L/LF-9400C	_	175	us
t _{DPPINIT}	PROGRAMN low to	NITN low	_	150	ns
t _{DPPDONE}	PROGRAMN low to	DONE low	_	150	ns
t _{IODISS}	PROGRAMN low to	o I/O disable	_	120	ns
Slave SPI					
f _{MAX}	CCLK clock frequer	псу		66	MHz
t _{CCLKH}	CCLK clock pulse v	vidth high	7.5	—	ns
t _{CCLKL}	CCLK clock pulse v	vidth low	7.5	_	ns
t _{STSU}	CCLK setup time		2	_	ns
t _{STH}	CCLK hold time		0	_	ns
t _{STCO}	CCLK falling edge t	o valid output	—	10	ns
t _{STOZ}	CCLK falling edge t	o valid disable	—	10	ns
t _{STOV}	CCLK falling edge t	o valid enable	—	10	ns
t _{SCS}	Chip select high tim	ne	25	—	ns
t _{SCSS}	Chip select setup ti	me	3	—	ns
t _{SCSH}	Chip select hold tim	ne	3	—	ns
Master SPI					
f _{MAX}	MCLK clock freque	ncy	_	133	MHz
t _{MCLKH}	MCLK clock pulse v	vidth high	3.75	—	ns
t _{MCLKL}	MCLK clock pulse v	width low	3.75	—	ns
t _{STSU}	MCLK setup time		5	—	ns
t _{STH}	MCLK hold time		1	—	ns
t _{CSSPI}	INITN high to chip s	select low	100	200	ns
t _{MCLK}	INITN high to first M	ICLK edge	0.75	1	US



Signal Descriptions (Cont.)

Signal Name	I/O	Descriptions					
Configuration (Dual fu	Configuration (Dual function pins used during sysCONFIG)						
PROGRAMN	I	Initiates configuration sequence when asserted low. This pin always has an active pull-up.					
INITN	I/O	Open Drain pin. Indicates the FPGA is ready to be configured. During configuration, a pull-up is enabled.					
DONE	I/O	Open Drain pin. Indicates that the configuration sequence is complete, and the start-up sequence is in progress.					
MCLK/CCLK	I/O	Input Configuration Clock for configuring an FPGA in Slave SPI mode. Output Configuration Clock for configuring an FPGA in SPI and SPIm configuration modes.					
SN	I	Slave SPI active low chip select input.					
CSSPIN	I/O	Master SPI active low chip select output.					
SI/SPISI	I/O	Slave SPI serial data input and master SPI serial data output.					
SO/SPISO	I/O	Slave SPI serial data output and master SPI serial data input.					
SCL	I/O	Slave I ² C clock input and master I ² C clock output.					
SDA	I/O	Slave I ² C data input and master I ² C data output.					



			Ма	chXO3L/LF	-4300		
	WLCSP81	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324	CABGA400
General Purpose IO per Bank							
Bank 0	29	24	50	71	50	71	83
Bank 1	0	26	52	62	52	68	84
Bank 2	20	26	52	72	52	72	84
Bank 3	7	7	16	22	16	24	28
Bank 4	0	7	16	14	16	16	24
Bank 5	7	10	20	27	20	28	32
Total General Purpose Single Ended IO	63	100	206	268	206	279	335
Differential IO per Bank							
Bank 0	15	12	25	36	25	36	42
Bank 1	0	13	26	30	26	34	42
Bank 2	10	13	26	36	26	36	42
Bank 3	3	3	8	10	8	12	14
Bank 4	0	3	8	6	8	8	12
Bank 5	3	5	10	13	10	14	16
Total General Purpose Differential IO	31	49	103	131	103	140	168
Dual Function IO	25	37	37	37	37	37	37
Number 7:1 or 8:1 Gearboxes							
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	10	7	18	18	18	18	21
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	10	13	18	18	18	18	21
High-speed Differential Outputs							
Bank 0	10	7	18	18	18	18	21
VCCIO Pins							
Bank 0	3	1	4	4	4	4	5
Bank 1	0	1	3	4	4	4	5
Bank 2	2	1	4	4	4	4	5
Bank 3	1	1	2	2	1	2	2
Bank 4	0	1	2	2	2	2	2
Bank 5	1	1	2	2	1	2	2
VCC	4	4	8	8	8	10	10
GND	6	10	24	16	24	16	33
NC	0	0	0	13	1	0	0
Reserved for Configuration	1	1	1	1	1	1	1
Total Count of Bonded Pins	81	121	256	324	256	324	400



Date	Version	Section	Change Summary
September 2015	1.5	DC and Switching Characteristics	Updated the MIPI D-PHY Emulation section. Revised Table 3-5, MIPI D- PHY Output DC Conditions. — Revised RL Typ. value. — Revised RH description and values.
			Updated the Maximum sysIO Buffer Performance section. Revised MIPI Max. Speed value.
			Updated the MachXO3L/LF External Switching Characteristics – C/E Devices section. Added footnotes 14 and 15.
August 2015	1.4	Architecture	Updated the Device Configuration section. Added JTAGENB to TAP dual purpose pins.
		Ordering Information	Updated the top side markings section to indicate the use of LMXO3LF for the LCMXO3LF device.
March 2015	1.3	All	General update. Added MachXO3LF devices.
October 2014	1.2	Introduction	Updated Table 1-1, MachXO3L Family Selection Guide. Revised XO3L- 2100 and XO3L-4300 IO for 324-ball csfBGA package.
		Architecture	Updated the Dual Boot section. Corrected information on where the pri- mary bitstream and the golden image must reside.
		Pinout Information	Updated the Pin Information Summary section.
			Changed General Purpose IO Bank 5 values for MachXO3L-2100 and MachXO3L-4300 CSFBGA 324 package.
			Changed Number 7:1 or 8:1 Gearboxes for MachXO3L-640 and MachXO3L-1300.
			Removed DQS Groups (Bank 1) section.
			Changed VCCIO Pins Bank 1 values for MachXO3L-1300, MachXO3L- 2100, MachXO3L-4300 and MachXO3L-6900 CSFBGA 256 package.
			Changed GND values for MachXO3L-1300, MachXO3L-2100, MachXO3L-4300 and MachXO3L-6900 CSFBGA 256 package.
			Changed NC values for MachXO3L-2100 and MachXO3L-4300 CSF- BGA 324 package.
		DC and Switching Characteristics	Updated the BLVDS section. Changed output impedance nominal values in Table 3-2, BLVDS DC Condition.
			Updated the LVPECL section. Changed output impedance nominal value in Table 3-3, LVPECL DC Condition.
			Updated the sysCONFIG Port Timing Specifications section. Updated INITN low time values.
July 2014	1.1	DC and Switching Characteristics	Updated the Static Supply Current – C/E Devices section. Added devices.
			Updated the Programming and Erase Supply Current – C/E Device section. Added devices.
			Updated the sysIO Single-Ended DC Electrical Characteristics section. Revised footnote 4.
			Added the NVCM Download Time section.
			Updated the Typical Building Block Function Performance – C/E Devices section. Added information to footnote.
		Pinout Information	Updated the Pin Information Summary section.
		Ordering Information	Updated the MachXO3L Part Number Description section. Added packages.
			Updated the Ordering Information section. General update.





Date	Version	Section	Change Summary
June 2014	1.0	—	Product name/trademark adjustment.
		Introduction	Updated Features section.
			Updated Table 1-1, MachXO3L Family Selection Guide. Changed fcCSP packages to csfBGA. Adjusted 121-ball csfBGA arrow.
			Introduction section general update.
		Architecture	General update.
		DC and Switching Characteristics	Updated sysIO Recommended Operating Conditions section. Removed V _{REF} (V) column. Added standards.
			Updated Maximum sysIO Buffer Performance section. Added MIPI I/O standard.
			Updated MIPI D-PHY Emulation section. Changed Low Speed to Low Power. Updated Table 3-4, MIPI DC Conditions.
			Updated Table 3-5, MIPI D-PHY Output DC Conditions.
			Updated Maximum sysIO Buffer Performance section.
			Updated MachXO3L External Switching Characteristics – C/E Device section.
May 2014	00.3	Introduction	Updated Features section.
			Updated Table 1-1, MachXO3L Family Selection Guide. Moved 121-ball fcCSP arrow.
			General update of Introduction section.
		Architecture	General update.
		Pinout Information	Updated Pin Information Summary section. Updated or added data on WLCSP49, WLCSP81, CABGA324, and CABGA400 for specific devices.
		Ordering Information	Updated MachXO3L Part Number Description section. Updated or added data on WLCSP49, WLCSP81, CABGA324, and CABGA400 for specific devices.
			Updated Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Added part numbers.
February 2014	00.2	DC and Switching Characteristics	Updated MachXO3L External Switching Characteristics – C/E Devices table. Removed LPDDR and DDR2 parameters.
	00.1		Initial release.